



Photocouplers

LTV-0601(Preliminary Version)

Data Sheet

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I. DESCRIPTION

The LTV-0601 consists of a high efficient AlGaAs Light Emitting Diode and a high speed optical detector. This design provides excellent AC and DC isolation between the input and output sides of the Optocoupler. The output of the optical detector features an open collector Schottky clamped transistor. The enable function allows the optical detector to be strobed. A guaranteed common mode transient immunity is up to 15,000V/ μ s.

The Optocoupler operational parameters are guaranteed over the temperature range from -40°C ~ +85°C.

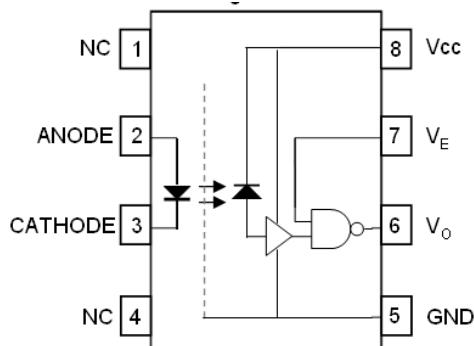
1.1 Features

- SO8 package
- High speed – 10MBd typical
- Guaranteed AC and DC performance over temperature -40°C ~ +85°C.
- LSTTL/TTL Compatible.
- Strobable output.

1.2 Applications

- Isolation in line receivers
- Ground loop elimination
- Feedback Element in Switching Mode Power Supplier
- High Speed Logic Ground Isolation – TTL/TTL, TTL/CMOS, TTL/LSTTL
- Pulse transformer replacement
- Power transistor isolation in motor drives
- Interface between Microprocessor system, computer and their peripheral

1.3 Functional Diagram

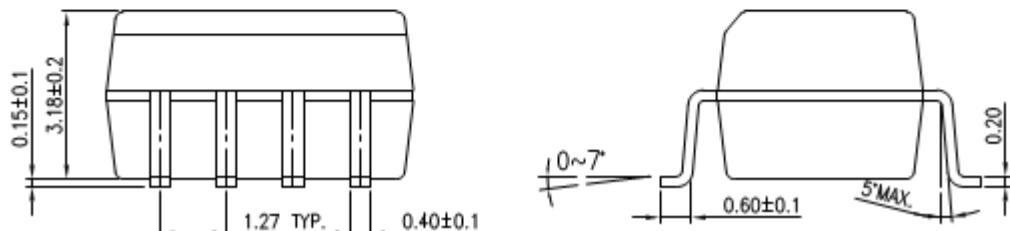
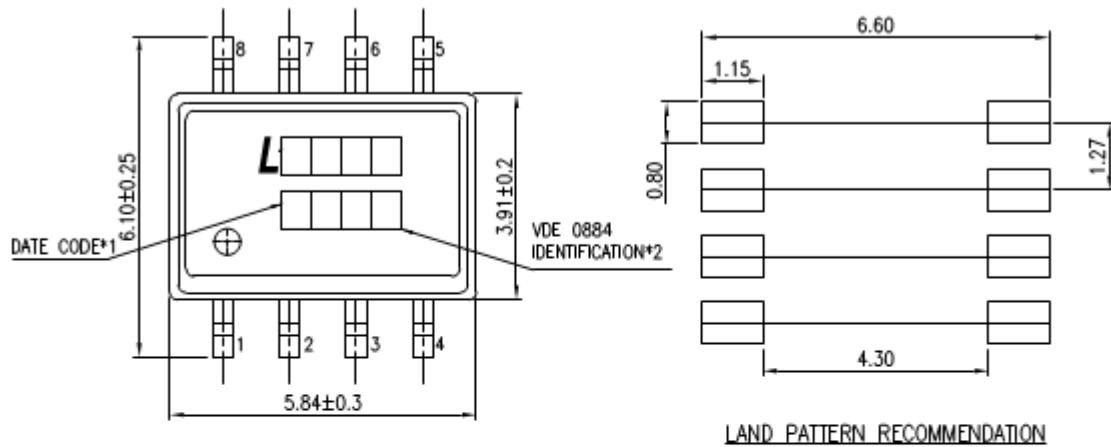


Truth Table (Positive Logic)

LED	ENABLE	OUT
ON	H	L
OFF	H	H
ON	L	H
OFF	L	H
ON	NC	L
OFF	NC	H

A 0.1 μ F bypass Capacitor must be
connected between Pin8 and Pin5

2. PACKAGE DIMENSIONS

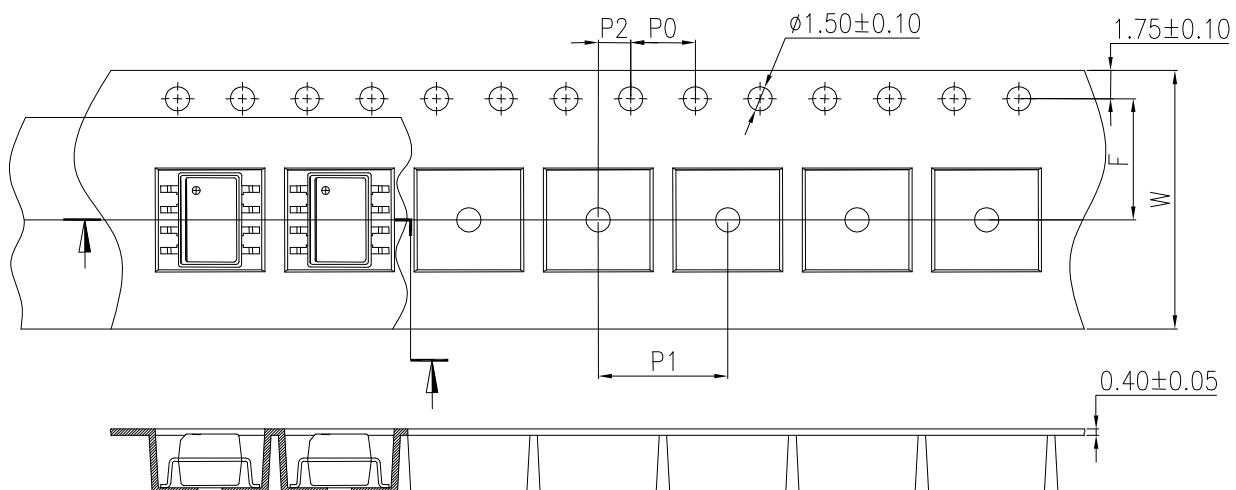


Part No : LTV-0601

Notes :

1. Date code
2. "V" to represent VDE0884
3. Date code
4. Dimensions are all in Millimeters.

3. TAPING DIMENSIONS



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (0.63)
Pitch of sprocket holes	P ₀	4±0.1 (0.15)
Distance of compartment	F	7.5±0.1 (0.295)
	P ₂	2±0.1 (0.079)
Distance of compartment to compartment	P ₁	8±0.1 (0.47)

Quantities Per Reel

Package Type	LTV-0601
Quantities (pcs)	2000

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4. RATING AND CHARACTERISTICS

4.1 Absolute Maximum Ratings at Ta=25°C *1

	Parameter	Symbol	Rating	Unit
Input	Average Forward Input Current	I _F	20	mA
	Reverse Input Voltage	V _R	5	V
	Power Dissipation	P _I	35	mW
	Enable Input Voltage	V _E	Vcc+5	V
	Enable Input current	I _E	5	mA
Output	Output Collector Current	I _O	50	mA
	Output Collector Voltage	V _O	7	V
	Output Collector Power Dissipation	P _O	85	mW
	Isolation Voltage	V _{iso}	3750	V _{rms}
	Supply Voltage	V _{CC}	7	V
	Operating Temperature	T _{opr}	-55 ~ +85	°C
	Storage Temperature	T _{stg}	-55 ~ +125	°C
	Lead Solder Temperature *2	T _{sol}	260	°C

1. Ambient temperature = 25°C, unless otherwise specified. Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.
2. 260°C for 10 seconds. Refer to Lead Free Reflow Profile.

4.2 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Operating Temperature	T _A	-40	85	°C
Supply Voltage	V _{CC}	4.5	5.5	V
Low Level Input Current	I _{FL}	0	250	µA
High Level Input Current	I _{FH}	5	15	mA
Low Level Enable Voltage	V _{EL}	0	0.8	V
High Level Enable Voltage	V _{EH}	2	V _{CC}	V
Output Pull-up Resistor	R _L	330	4k	Ω
Fan Out (at R _L =1kΩ per channel)	N	—	5	TTL Loads

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4.3 ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Input						
Input Forward Voltage	V _F	—	1.38	1.8	V	I _F = 10mA
Input Forward Voltage Temperature Coefficient	ΔV _F / ΔT	—	-1.6	—	mV/°C	I _F = 10mA
Input Reverse Voltage	BV _R	5.0	—	—	V	I _R = 10μA
Input Threshold Current	I _{TH}	—	1.35	5	mA	V _E = 2V, V _{CC} = 5.5V,
		—	2 ⁽¹⁾	3	mA	I _{OL} (sinking) = 13mA
Input Capacitance	C _{IN}	—	34	—	pF	f = 1MHz, V _F = 0V
Detector						
High Level Supply Current	I _{CCH}	—	7.4	10	uA	V _E = 0.5V, V _{CC} = 5.5V, I _F = 0mA
Low Level Supply Current	I _{CCL}	—	10	13	mA	V _E = 0.5V, V _{CC} = 5.5V, I _F = 10mA
High Level Enable Current	I _{EH}	—	-0.6	-1.6	mA	V _E = 2V
Low Level Enable Current	I _{EL}	—	-0.9	-1.6	mA	V _E = 0.5V
High Level Enable Voltage	V _{EH}	2	—	—	V	
Low Level Enable Voltage	V _{EL}		—	0.8	V	
High Level Output Current	I _{OH}	—	—	100	μA	V _E = 2V, V _{CC} = 5.5V, V _O = 5.5V, I _F = 250μA
Low Level Output Voltage	V _{OL}	—	0.25	0.60	V	V _E = 2V, V _{CC} = 5.5V, I _F = 5mA, I _{OL} (sinking) = 13mA

Specified over recommended temperature (T_A = -40°C to +85°C) unless otherwise specified. Typical values applies to V_{CC} = 5V,

T_A = 25°C. See note 1.

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5. SWITCHING SPECIFICATION

$T_A=0\sim70^\circ C$, $V_{CC}=5V$, unless otherwise specified.

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition	Note
Propagation Delay Time to Low Output Level	t_{PHL}	25	40	100	ns	$R_L = 350\Omega$, $C_L = 15pF$	3
Propagation Delay Time to High Output Level	t_{PLH}	25	27	100	ns	$R_L = 350\Omega$, $C_L = 15pF$	4
Pulse Width Distortion	$ t_{PLH} - t_{PHL} $	—	12	—	ns	$R_L = 350\Omega$, $C_L = 15pF$	—
Propagation Delay Skew	t_{PSK}	—	—	—	—	$R_L = 350\Omega$, $C_L = 15pF$	—
Output Rise Time (10 to 90%)	t_r	—	20	—	ns	$R_L = 350\Omega$, $C_L = 15pF$	—
Output Fall Time (90 to 10%)	t_f	—	6.6	—	ns	$R_L = 350\Omega$, $C_L = 15pF$	—
Propagation Delay Time of Enable from V_{EH} to V_{EL}	t_{ELH}	—	28	—	ns	$R_L = 350\Omega$, $C_L = 15pF$, $V_{EL} = 0V$, $V_{EH} = 3V$	5
Propagation Delay Time of Enable from V_{EL} to V_{EH}	t_{EHL}	—	12	—	V/μs	$R_L = 350\Omega$, $C_L = 15pF$, $V_{EL} = 0V$, $V_{EH} = 3V$	6
Logic High Common Mode Transient Immunity	$ CM_H $	1,000	—	—	V/μs	$ V_{CM} = 20V$, $V_{CC} = 5V$, $I_F = 0mA$, $V_{O(MIN)} = 2V$, $R_L = 350\Omega$, $T_A = 25^\circ C$	7,9
Logic Low Common Mode Transient Immunity	$ CM_L $	1,000	—	—	ns	$ V_{CM} = 20V$, $V_{CC} = 5V$, $I_F = 7.5mA$, $V_{O(MIN)} = 0V$, $R_L = 350\Omega$, $T_A = 25^\circ C$	8,9

*All Typical at $T_A=25^\circ C$

6. ISOLATION CHARACTERISTIC

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition	Note
Input-Output Insulation Leakage Current	I _{I-O}	—	—	1.0	μA	45% RH, t = 5s, V _{I-O} = 3kV DC, T _A = 25°C	10,11
Withstand Insulation Test Voltage	V _{IISO}	3750	—	—	V _{RMS}	RH ≤ 50%, t = 1min, T _A = 25°C	10,11,12
Input-Output Resistance	R _{I-O}	—	10 ¹²	—	Ω	V _{I-O} = 500V DC	10
Input-Output Capacitance	C _{I-O}	—	1.0	—	p	f = 1MHz, T _A = 25°C	10

Specified over recommended temperature (T_A = -40°C to +85°C) unless otherwise specified. Typical values applies to T_A = 25°C

Notes

1. A 0.1μF or bigger bypass capacitor for V_{CC} is needed as shown in Fig.1
2. Peaking driving circuit may be used to speed up the LED. The peak drive current of LED may go up to 50mA and maximum pulse width 50ns, as long as average current doesn't exceed 20mA.
3. t_{PLH} (propagation delay) is measured from the 3.75 mA point on the falling edge of the input pulse to the 1.5 V point on the rising edge of the output pulse.
4. t_{PHL} (propagation delay) is measured from the 3.75 mA point on the rising edge of the input pulse to the 1.5 V point on the falling edge of the output pulse.
5. The t_{EELH} enable propagation delay is measured from the 1.5 V point on the falling edge of the enable input pulse to the 1.5 V point on the rising edge of the output pulse.
6. The t_{EELL} enable propagation delay is measured from the 1.5 V point on the rising edge of the enable input pulse to the 1.5 V point on the falling edge of the output pulse.
7. CM_H is the maximum tolerable rate of rise of the common mode voltage to assure that the output will remain in a high logic state (i.e., VO > 2.0 V).
8. CM_L is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state (i.e., VO < 0.8 V).
9. No external pull up is required for a high logic state on the enable input. If the enable pin is not used, tying it to V_{CC}.
10. Device is considered a two-terminal device: pins 1, 2, 3, and 4 shorted together, and pins 5, 6, 7, and 8 shorted together.
11. In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage 3000 V rms for one second (leakage current less than 5 uA). This test is performed before the 100% production test for partial discharge

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7. SWITCHING TIME TEST CIRCUIT

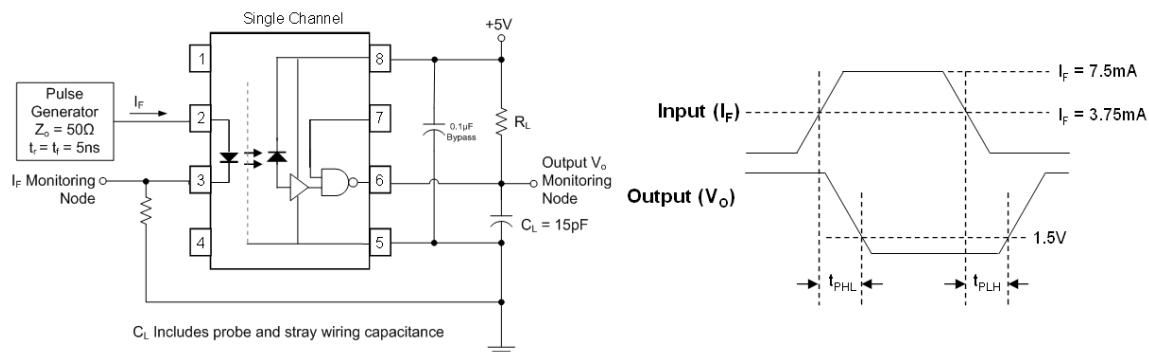


Figure 1: Single Channel Test Circuit for t_{PHL} and t_{PLH}

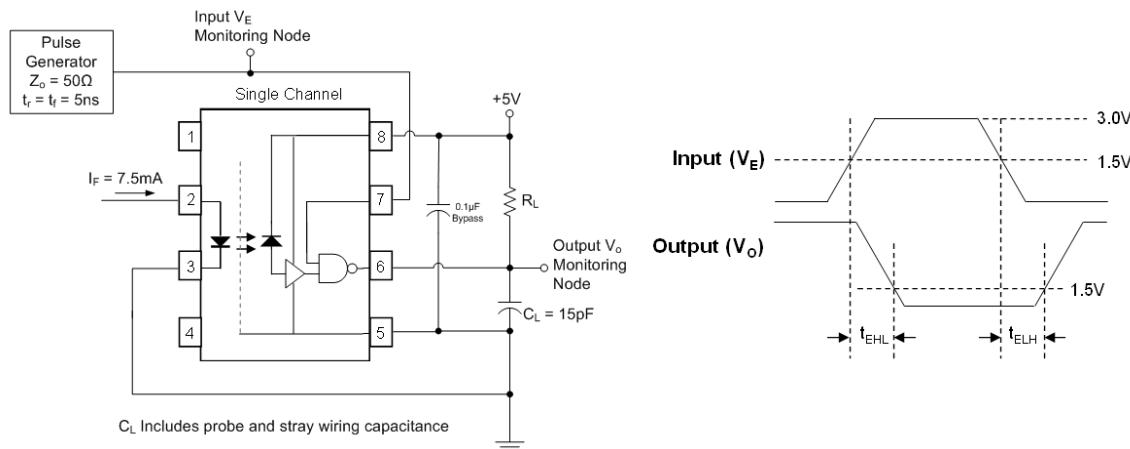


Figure 2: Single Channel Test Circuit for Common Mode Transient Immunity

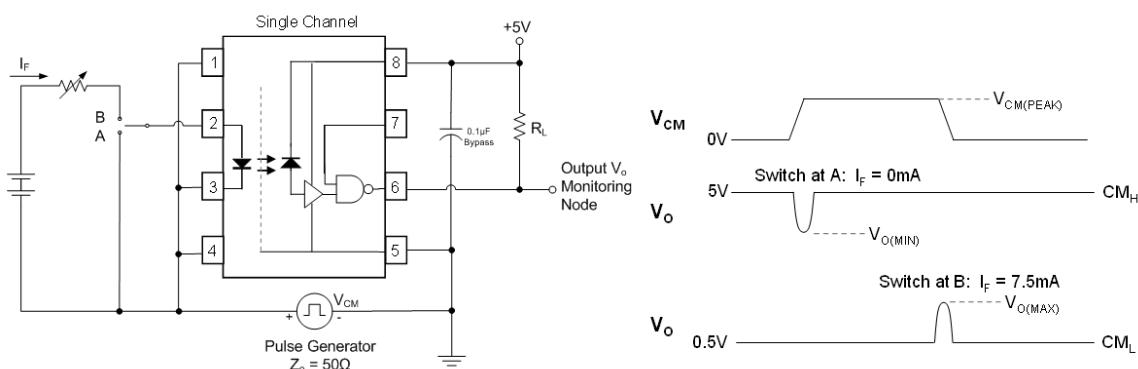


Figure 3: Single Channel Test Circuit for Common Mode Transient Immunity

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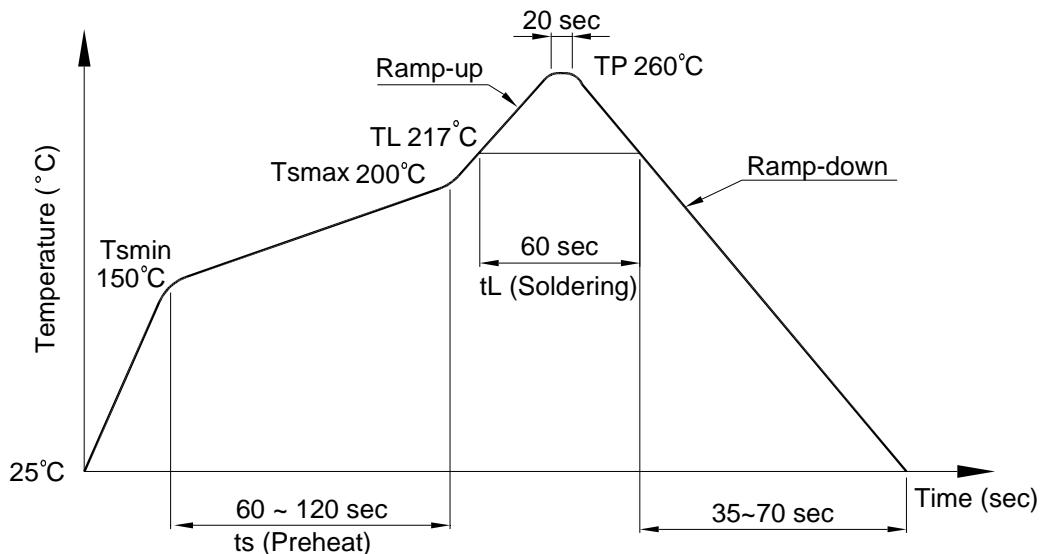
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8. TEMPERATURE PROFILE OF SOLDERING

8.1 IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

Profile item	Conditions
Preheat	
- Temperature Min (T_{Smin})	150°C
- Temperature Max (T_{Smax})	200°C
- Time (min to max) (t_s)	90±30 sec
Soldering zone	
- Temperature (T_L)	217°C
- Time (t_L)	60 sec
Peak Temperature (T_P)	260°C
Ramp-up rate	3°C / sec max.
Ramp-down rate	3~6°C / sec



8.2 Wave soldering (JEDEC22A111 compliant)

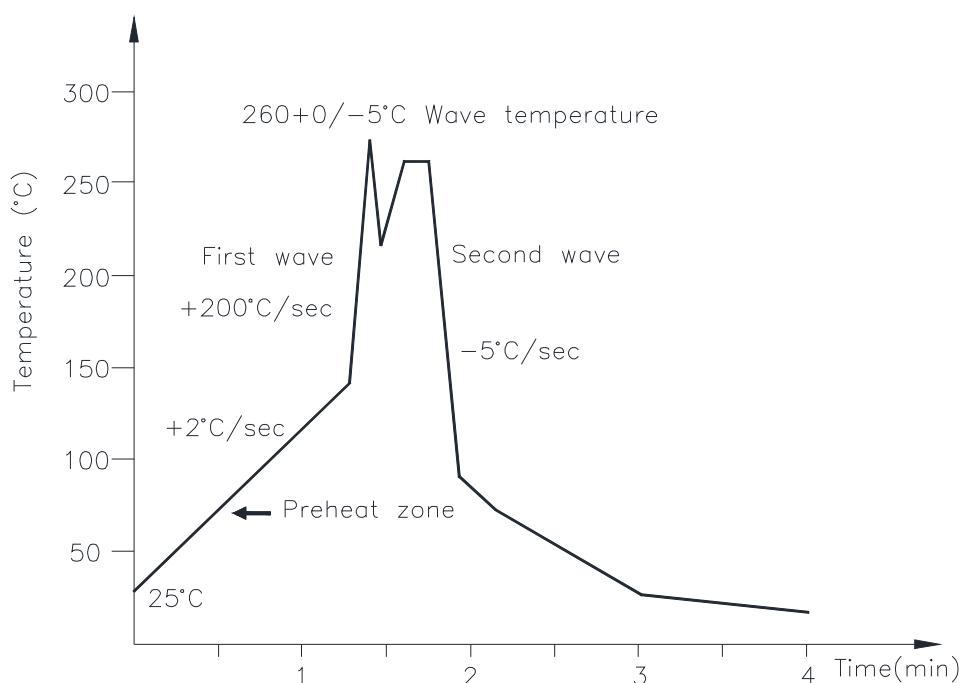
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C

Time: 10 sec.

Preheat temperature: 25 to 140°C

Preheat time: 30 to 80 sec.



8.3 Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature: 380+0/-5°C

Time: 3 sec max.

9. Notes:

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